NSN 5961-00-853-5975

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Inclosure Material:

Metal

Overall Length:

0.375 inches

Terminal Length:

0.789 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Terminal Circle Diameter:

0.215 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, emitter-to-base, collector open and 75.0

breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

3.00 amperes source cutoff current and 2.00 amperes source cutoff current

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

2 pin and 1 case

Specification Data:

80131-release3324 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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